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# Adsorption of Molecules on Nitrogen-Doped Graphene: A First-Principles Study

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We study the adsorption of  $NH_3$  and  $H_2O$  molecules on pyridine-type nitrogen-doped graphene using a first-principles electronic-structure calculation. The adsorption energies of  $NH_3$  and  $H_2O$  molecules on the pyridine-type defect are calculated and it is found that the adsorptions of  $NH_3$  as well as  $H_2O$  molecules become energetically favorable. The pyridine-type defect in N-doped graphene is therefore expected to be highly reactive, and should be useful for reaction centers in chemical processes as well as for sensor applications.

**KEYWORDS:** Density-functional theory, Nitrogen-doped graphene, Molecular adsorption

## 1. Introduction

Graphene has attracted much attention from the viewpoint of fundamental physics and applicable systems in nanoelectronics since it possesses unique and excellent mechanical, electronic, and optical properties [1]. Especially, due to the extremely high carrier mobility, graphene is expected to be a good candidate for future nanoelectronics device materials [2].

Chemical functionalization should be an effective way to tune the electronic structures of carbon-based materials. Actually, the adsorption of NH<sub>3</sub> and H<sub>2</sub>O on graphene as well as carbon nanotubes (CNTs) has been studied and it is expected to be useful for sensor applications [3, 4]. It is also well-known that substitutional doping is a practical way to modify electronic structures of graphene and CNTs, and therefore the molecular adsorption can be often enhanced by substitutional dopants. For example, nitrogen is a good dopant for carbon-based materials, and the adsorption of molecules on N-doped graphene and CNTs have been studied [5, 6, 7]. However, the knowledge as to the adsorption of molecules on N-doped graphene is still limited since it has been reported that there are several nitrogen-defect configurations in graphene [8, 9].

In this report, we study the adsorption of  $NH_3$  and  $H_2O$  molecules upon nitrogen-doped graphene using a first-principles total-energy calculation within the framework of the density-functional theory. As the nitrogen defect in graphene to be studied, we consider the pyridine-type defect which consists of three nitrogen atoms around a single vacancy. The adsorption energies of  $NH_3$  and  $H_2O$  molecules on N-doped graphene are calculated, and it is found that the adsorption of  $NH_3$  and  $H_2O$  molecules becomes energetically favorable.

#### 2. Computational methods

The model system we study here consists of  $4 \times 4$  unit cell in the direction parallel to the graphene sheet, and therefore the pyridine-type defective graphene sheet contains 28 C atoms and 3 N atoms. In Fig. 1(a), the optimized atomic structure of pyridine-type defective graphene is illustrated. Figures 1(b) and (c) show the optimized atomic geometries of NH<sub>3</sub> and H<sub>2</sub>O adsorbed on the pyridine-type graphenes, respectively.

Our calculations are carried out using the first-principles total-energy methods within the density-functional theory [10, 11]. The interactions between the ions and the valence electrons are described by the norm-conserving Troullier-Martins pseudopotentials [12], and exchange-correlation effects are treated using the local density approximation (LDA) parameterized by Perdew and Zunger [13, 14]. The wave functions are expanded in a plane-wave basis and the kinetic-energy cutoff is taken to be 50 Ry [15]. The atomic positions are optimized until the Hellmann-Feynman force on each atom becomes less than 0.05 eV/Å. Two-dimensional Brillouin-zone integration is performed with 36 k-point sampling.

#### 3. Results and discussion

#### 3.1 Energetics

To discuss the stabilities of NH<sub>3</sub> and H<sub>2</sub>O molecules adsorbed on the pyridine-type N-doped graphene, we calculate the adsorption energy  $E_a$  defined as

$$E_a = E_{tot} - E_{sub} - E_{mol} \,, \tag{1}$$

where  $E_{tot}$  and  $E_{sub}$  are total energies of pyridine-type N-doped graphene with and without molecules, respectively, and  $E_{mol}$  is also total energy of the isolated molecule. Table I shows the adsorption energies of NH<sub>3</sub> and H<sub>2</sub>O molecules on N-doped

Table I shows the adsorption energies of NH<sub>3</sub> and H<sub>2</sub>O molecules on N-doped graphene. We find that the NH<sub>3</sub> molecule is dissociated into H and NH<sub>2</sub>, and they bind with two N atoms in the pyridine-type defect (see Fig. 1(b)). We find that the adsorption of NH<sub>3</sub> molecule on the pyridine-type defect becomes energetically favorable. In Ref. [6], it has been reported that the adsorption of the NH<sub>3</sub> molecule on the substitutional N



Fig. 1. (Color online) Optimized atomic geometries of N-doped graphenes: (a) the pyridine-type defect, (b)  $NH_3$  adsorbed on the pyridine-type defect, and (c)  $H_2O$  adsorbed on the pyridine-type defect.

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defective graphene, where one C atom is replaced by one N atom, is also favorable in energy. However, the

adsorption energy in the case of pyridine-type defective graphene (-1.214 eV) is much lower than that in the case of the substitutional N defective graphene (-0.015 eV) [6].

Table I. Adsorption energies of  $NH_3$  and  $H_2O$  molecules on pyridine-type graphene.

Adsorbed molecules	Adsorption energy (eV)
NH <sub>3</sub>	-1.214
$H_2O$	-0.769

For the adsorption of H<sub>2</sub>O molecule, it is dissociated into H and OH, and they are also adsorbed on two N atoms in the pyridine-type defect (Fig. 1(c)). It is found that the adsorption of H<sub>2</sub>O molecule also becomes energetically preferable, and its adsorption energy (-0.769 eV) is considerably lower than that for the adsorption on the substitutional N defect (-0.06 eV) [6]. The pyridine-type defect, thus, is found to be more reactive compared with the substitutional N defect. Moreover, the adsorption of NH<sub>3</sub> molecule is found to be preferred in energy rather than that of the H<sub>2</sub>O molecule.

#### 3.2 Geometry

We study the atomic geometries of NH<sub>3</sub> and H<sub>2</sub>O molecules on N-doped graphene, as shown in Figs. 1(b) and (c), respectively. For the adsorption of NH<sub>3</sub> molecule, two bond angles of H-N-N bonds in the NH<sub>2</sub> adsorption site are 107.4° and 108.5° [Figs. 1(b)]. Two N-H bond lengths and N-N bond length in the NH<sub>2</sub> site are both 1.03 Å and 1.41 Å, respectively. Our calculated N-H bond length and the H-N-H bond angle of the isolated NH<sub>3</sub> molecule are 1.02 Å and 107.2°, respectively. For the adsorption of H<sub>2</sub>O molecule, the lengths of O-H and N-O bonds are 1.02 Å and 1.41 Å, respectively, and the bond angle of H-O-N is 99.4°. The bond length of O-H and the bond angle of H-O-H in the isolated H<sub>2</sub>O molecule are 0.98 Å and 104.3°, respectively. When NH<sub>2</sub> and OH are adsorbed at the N atoms in the pyridine-type defect, they keep similar configurations of isolated NH<sub>3</sub> and H<sub>2</sub>O molecules, respectively. On the other hand, the N atom in the pyridine-type defect protrudes from the planar graphene sheet by the adsorption of NH<sub>2</sub> and OH.

#### 4. Summary

We have studied the adsorption of  $NH_3$  and  $H_2O$  molecules on the pyridine-type defective graphene using a first-principles density-functional calculation. The adsorption energies of  $NH_3$  and  $H_2O$  molecules are calculated and the dissociative adsorptions of  $NH_3$  and  $H_2O$  molecules on the pyridine-type defect are found to be favored energetically.

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